Round Through-Hole LED Lamp (5 mm)



OVLFx3C7 Series

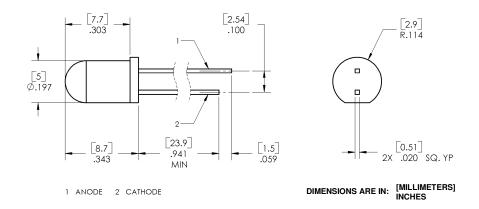
- · High brightness with well-defined spatial radiation patterns
- UV-resistant epoxy lens
- Blue, green, red, yellow

Each device in the **OVLFx3C7** series is a high-intensity LED mounted in a clear plastic T-1³/₄ package. The LED provides a well-defined and even emission pattern. Its UV-resistant epoxy lens makes this device an optimal solution for outdoor applications.

Applications

- Traffic and pedestrian signals
- Signage and architectural lighting
- Backlighting
- Automotive

Part Number	Material	Emitted Color	Intensity Typ. mcd	Lens Color
OVLFB3C7	InGaN	Blue	2000	Water Clear
OVLFG3C7	InGaN	Green	7000	Water Clear
OVLFR3C7	AllnGaP	Red	5000	Water Clear
OVLFY3C7	AllnGaP	Yellow	4000	Water Clear



Leadframe material is iron alloy with tin-plated leads







Absolute Maximum Ratings $T_A = 25^{\circ}$ C unless otherwise noted

Storage Temperature Range		-40 ~ +100 ℃
Operating Temperature Range		-40 ~ +85 ℃
Reverse Voltage		5 V
Continuous Forward Current	Blue, Green	20 mA
Continuous Forward Current	Red, Yellow	30 mA
Paals Formward Current (10% Puty Cuale, 1 kl la)	Blue, Green	50 mA
Peak Forward Current (10% Duty Cycle, 1 kHz)	Red, Yellow	100 mA
Deven Dissingtion	Blue, Green	80 mW
Power Dissipation	Red, Yellow	72 mW
Current Linearity vs Ambient Temperature Blue, Green Red, Yellow		-0.2 mA/° C
		-0.5 mA/° C
LED Junction Temperature	·	125°C
Lead Soldering Temperature (4 mm from the base of the epoxy b	260 ° C / 5 seconds	

Electrical Characteristics

 $T_A = 25^{\circ} C$ unless otherwise noted

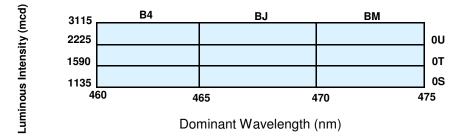
SYMBOL	PARAMETER	COLOR	MIN	TYP	МАХ	UNITS	CONDITIONS	
		Blue	1135	2000			L 00 m A	
	Luminous Intensity	Green	4360	7000		mod		
Iv	Luminous Intensity	Red	2820	5000		mcd	I _F = 20 mA	
		Yellow	2225	4000				
		Blue		3.4	4.0			
V _F	Forward Voltage	Green	2.6	3.4	4.0	v	I _F = 20 mA	
۷F	Torward voltage	Red		2.0	2.4	v	$I_F = 20 IIIA$	
		Yellow		2.0	2.4			
		Blue			50			
I _R	Reverse Current	Green			50	μA	V _R = 5 V	
		Red			10			
		Yellow			10			
		Blue	460	465	475			
3	Dominant Wavelength	Green	519	525	531	nm	I _F = 20 mA	
λ_{D}	Dominant wavelength	Red	620	625	630	nm	$I_F = 20 IIIA$	
		Yellow	585	589	595			
		Blue		25				
A.)		Green		25		nm	I 20 mA	
Δλ	Spectra Half Width	Red		25			I _F = 20 mA	
		Yellow		25]		
2⊖½H-H	50% Power Angle	·		30		deg	I _F = 20 mA	



Standard Bins $(I_F = 20 \text{ mA})$

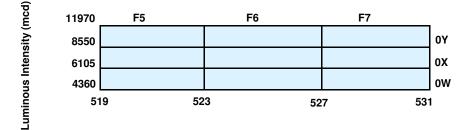
Lamps are sorted to luminous intensity (I_V) and dominant wavelength (λ_D) bins shown. Orders may be filled with any or all bins contained as below.

OVLFB3C7 (BLUE)



Forward Voltage (V _F)							
Rank	Н	J	K	L			
Voltage	2.6–3.0	3.0–3.3	3.3–3.6	3.6–4.0			

OVLFG3C7 (GREEN)



Dominant Wavelength (nm)

Forward Voltage (V _F	:)			
Rank	Н	J	К	L
Voltage	2.6–3.0	3.0–3.3	3.3–3.6	3.6–4.0

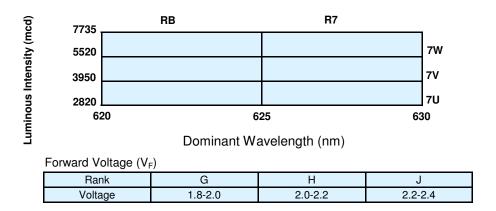
Notes:

- 1. All ranks will be included per delivery, rank ratio will be based on the chip distribution.
- 2. To designate luminous intensity ranks, please contact OPTEK.

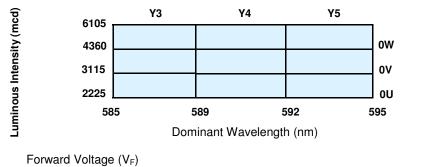
3. Pb content <1000 PPM.



OVLFR3C7 (RED)



OVLFY3C7 (YELLOW)

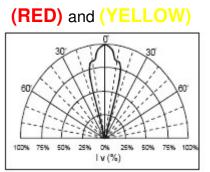


Rank	G	Н	J
Voltage	1.8–2.0	2.0-2.2	2.2-2.4

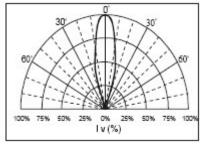
Important Notes:

- 1. All ranks will be included per delivery, rank ratio will be based on the chip distribution.
- 2. To designate luminous intensity ranks, please contact OPTEK.
- 3. Pb content <1000 PPM.

Beam Pattern

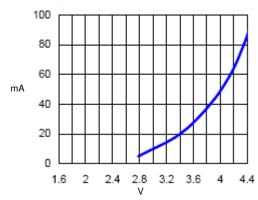


(BLUE) and (GREEN)

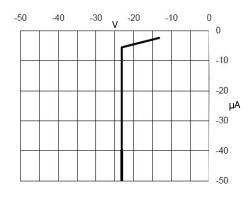




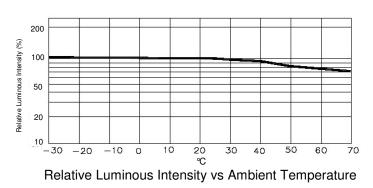
Typical Electro-Optical Characteristics Curves (BLUE)

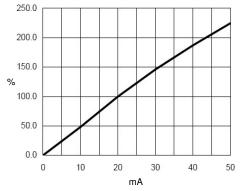


Forward Current vs Forward Voltage

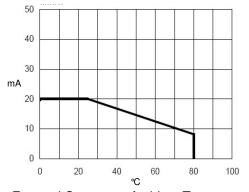


Reverse Current vs Reverse Voltage

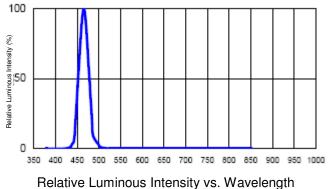




Relative Luminous Intensity vs Forward Current

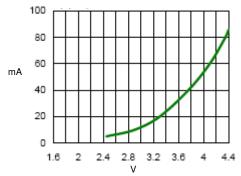


Forward Current vs Ambient Temperature

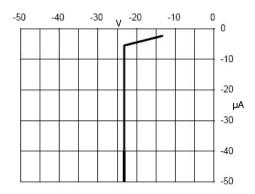




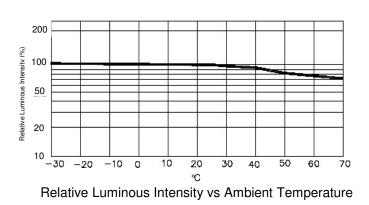
Typical Electro-Optical Characteristics Curves (GREEN)

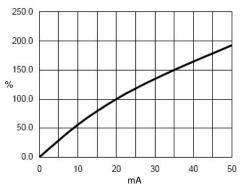


Forward Current vs Forward Voltage

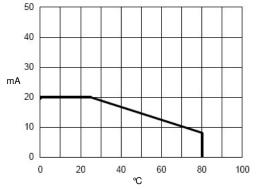


Reverse Current vs Reverse Voltage

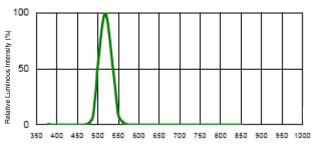




Relative Luminous Intensity vs Forward Current



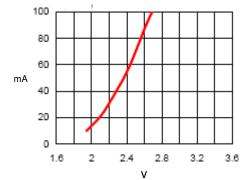
Forward Current vs Ambient Temperature



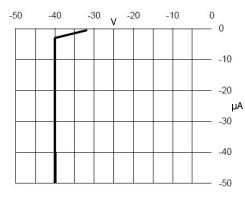
Relative Luminous Intensity vs. Wavelength



Typical Electro-Optical Characteristics Curves (RED)



Forward Current vs Forward Voltage



Reverse Current vs Reverse Voltage

200

100

50

20 10

-30 -20

-10 0

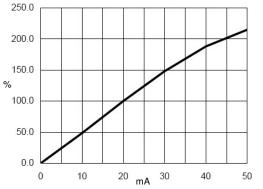
10

20 ℃

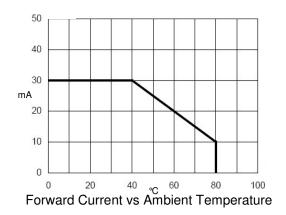
Relative Luminous Intensity vs Ambient Temperature

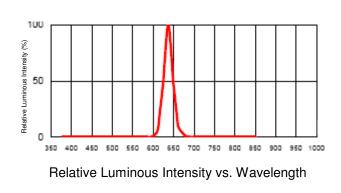
30 40

Relative Luminous Intensity (%)



Relative Luminous Intensity vs Forward Current





OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

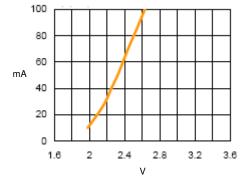
50

60

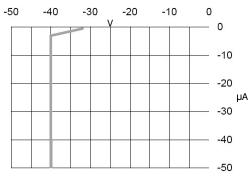
70



Typical Electro-Optical Characteristics Curves (YELLOW)



Forward Current vs Forward Voltage



Reverse Current vs Reverse Voltage

50

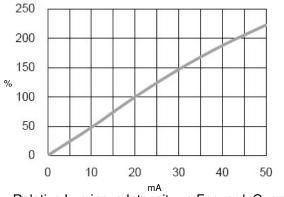
60

70

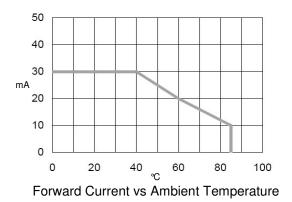
30 40

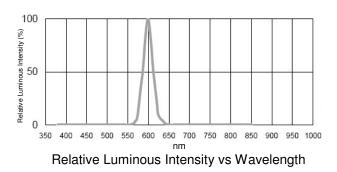
°C

Relative Luminous Intensity vs Ambient Temperature



Relative Luminous Intensity vs Forward Current





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200

50

20

10 -30

-20

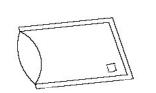
-10 0

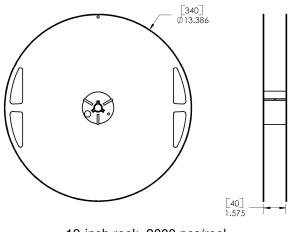
10 20

Relative Luminous Intensity (%)



Packing Information: Available in bulk or tape/reel

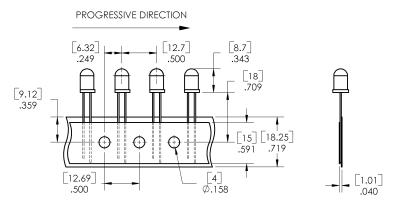




Bulk: 500 pcs/bag

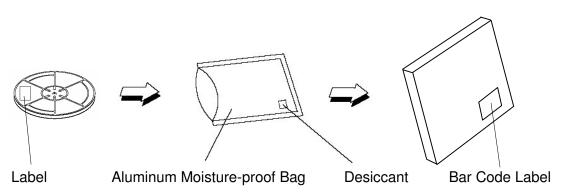
13-inch reel: 2000 pcs/reel

Carrier Tape Dimensions: Loaded quantity 2000 pieces per reel



DIMENSIONS ARE IN INCHES AND [MILLIMETERS].

Moisture Resistant Packaging





Reliability Test

LED lamps are checked by reliability tests based on MIL standards.

Classi- fication	Test Item	Standard Test Method	Test Conditions	Duration	Unit	Acc / Rej Criteria	Result
Life Test	Operation Life Test (OLT)	MIL-STD-750D Method 1026.3	$T_A=25^{\circ}C$, $I_F=30mA$ *	1000 Hrs	100	0 / 1	Pass
	High Temperature Storage (HTS)	MIL-STD-750D Method 1032.1	T _A =100°C	1000 Hrs	100	0 / 1	Pass
Test	Low Temperature Storage (LTS)	MIL-STD-750D Method 1032.1	$T_A = -40^{\circ}C$	1000 Hrs	100	0 / 1	Pass
Environment Test	Temp. & Humidity with Bias (THB)	MIL-STD-750D Method 103B	$T_A = 85^{\circ}C$, Rh=85% $I_F = 20mA **$	500 Hrs	100	0 / 1	Pass
Envi	Thermal Shock Test (TST)	MIL-STD-750D Method 1056.1	0°C ~ 100°C 2min 2min	100 cycles	100	0 / 1	Pass
	Temperature Cycling Test (TCT)	MIL-STD-750D Method 1051.5	-40°C ~ 25°C~ 100°C ~ 25°C 30min 5min 30min 5min	100 cycles	100	0 / 1	Pass
Test	Solderability	MIL-STD-750D Method 2026.4	235±5℃,5 sec	1 time	20	0 / 1	Pass
Mechanical Test	Resistance to Soldering Heat	MIL-STD-750D Method 2031.1	260±5℃ , 10 sec	1 time	20	0 / 1	Pass
Mec	Lead Integrity	MIL-STD-750D Method 2036.3	Load 2.5N (0.25kgf) 0°~90°~0°, bend	3 times	20	0 / 1	Pass

Remark : (*) $I_{\rm F}$ =30mA for AlInGaP chip ; $I_{\rm F}$ =20mA for InGaN chip

(**) $I_{\rm F}$ =20mA for AlInGaP chip $\ ; \ I_{\rm F}$ =10mA for InGaN chip

2. Failure Criteria (T_A=25℃):

Test Item	Symbol	Test Conditions	Criteria for Judgment			
Test Item	Symbol	Min.		Max.		
Luminous Intensity	$I_{\rm V}$	I _F =20 mA	LSL×0.7 **			
Voltage (Forward)	$V_{\rm F}$	I _F =20 mA		USL×1.1 *		

(*) USL : Upper Standard Level , (**) LSL : Lower Standard Level